NL17SZU04

Single Unbuffered Inverter

The NL17SZU04 is a single unbuffered inverter in two tiny footprint package. The device performs much as LCX multi-gate products in speed and drive.

Features

- Tiny SOT-353 and SOT-553 Packages
- Source/Sink ± 16 mA at 4.5 V V_{CC}
- Over–Voltage Tolerant Inputs and Outputs
- Pin For Pin with NC7SZU04P5X, TC7SZU04FU and TC7SZU04AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Pb–Free Packages are Available



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http://onsemi.com

MARKING DIAGRAMS

L6^d





SOT-553 **XV5 SUFFIX** CASE 463B

L6 = Device Marking D

= One Digit Date Code

PIN ASSIGNMENT

Pin	Function
1	NC
2	Ā
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

Input	Output Y = Ā
Α	Y
L	Н
Н	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Ο 5 NC Vcc Δ 2 4 GND 3

Figure 1. Pinout (Top View)



Figure 2. Logic Symbol

MAXIMUM RATINGS

Symbol	Paramete	r	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V	
V _{IN}	DC Input Voltage		-0.5 to $+7.0$	V
V _{OUT}	DC Output Voltage		-0.5 to $+7.0$	V
Ι _{ΙΚ}	DC Input Diode Current		-50	mA
I _{OK}	DC Output Diode Current	-50	mA	
I _{OUT}	DC Output Sink Current	±50	mA	
I _{CC}	DC Supply Current per Supply Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 10 Se	260	°C	
ΤJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance	SOT-353 (Note 1) SOT-553	350 496	°C/W
PD	Power Dissipation in Still Air at 85°C	SOT-353 SOT-553	186 135	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	Class IC Class A N/A	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22–A114–A, rated to EIA/JESD22–A114–B.

3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	DC Supply Voltage Data Re	(Operating) etention Only	1.65 1.5	5.5 5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage		0	5.5	V
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Rise and Fall Time $V_{CC} = 3$ $V_{CC} = 5$	3.0 V ±0.3 V 5.0 V ±0.5 V	0 0	100 20	ns/V

			Vcc	V_{CC} $T_A = 25$			$-40^{\circ}C \leq C$	$T_A \leq 85^\circ C$	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
VIH	High-Level Input Voltage		1.65 to 1.85	0.85 V _{CC}			0.85 V _{CC}		V
			2.3 to 5.5	0.8 V _{CC}			0.8 V _{CC}		1
V _{IL}	Low-Level Input Voltage		1.65 to 1.85			0.15 V _{CC}		0.15 V _{CC}	V
			2.3 to 5.5			0.2 V _{CC}		0.2 V _{CC}	
V _{OH}	High–Level Output Voltage V _{IN} = V _{IL} or V _{IH}	$I_{OH} = -100 \ \mu A$ $I_{OH} = -3 \ m A$	1.65 to 5.5 1.65	V _{CC} - 0.1 1.29	V _{CC} 1.52		V _{CC} – 0.1 1.29		V
		$I_{OH} = -4 \text{ mA}$	2.3	1.9	2.1		1.9		
		I _{OH} = -6 mA	2.7	2.2	2.4		2.2		
		I _{OH} = -8 mA	3.0	2.4	2.7		2.4		
		I _{OH} = -12 mA	3.0	2.3	2.5		2.3		
		I _{OH} = -16 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low–Level Output Voltage $V_{IN} = V_{IH} \text{ or } V_{OH}$	I _{OL} = 100 μA I _{OL} = 3 mA	1.65 to 5.5 1.65		0.08	0.1 0.24		0.1 0.24	V
		$I_{OL} = 4 \text{ mA}$	2.3		0.20	0.3		0.3	
		I _{OL} = 6 mA	2.7		0.22	0.4		0.4	
		I _{OL} = 8 mA	3.0		0.28	0.4		0.4	
		I _{OL} = 12 mA	3.0		0.38	0.55		0.55	
		I _{OL} = 16 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			±0.1		±1.0	μΑ
I _{OFF}	Power Off–Output Leakage Current	V _{OUT} = 5.5 V	0			1		10	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	1.65 to 5.5			1		10	μΑ

DC ELECTRICAL CHARACTERISTICS

AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 3.0 \text{ ns}$

			V _{CC}	T _A =	25°C	-40°C ≤ 1	Γ _A ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	R_L = 1 M Ω , C_L = 15 pF	1.8 ± 0.15	1.0	11.7	1.0	12.1	ns
t _{PHL}	t _{PHL} (Figure 3 and 4)	$R_L = 1 M\Omega$, $C_L = 15 pF$	2.5 ± 0.2	0.8	6.2	0.8	6.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	3.3 ± 0.3	0.5	4.5	0.5	4.8	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		1.0	6.0	1.0	6.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	5.0 ± 0.5	0.5	3.9	0.5	1.0	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		0.8	5.0	0.8	5.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	4.5	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	6.5	pF
	(Note 5)	10 MHz, V_{CC} = 5.5 V, V_I = 0 V or V_{CC}	10	

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

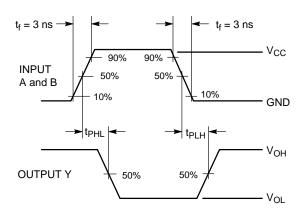
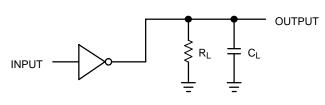


Figure 3. Switching Waveform



A 1-MHz square input wave is recommended for propagation delay tests.



DEVICE ORDERING INFORMATION

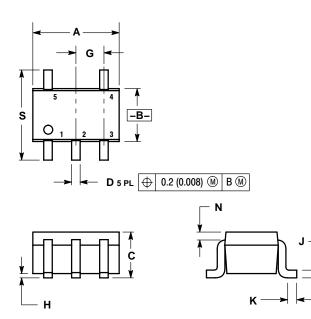
		Device Nomenclature							
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size †
NL17SZU04DFT2	NL	1	7	SZ	U04	DF	T2	SOT-353/ SC70-5/ SC-88A	178 mm, 3000 Unit
NL17SZU04DFT2G	NL	1	7	SZ	U04	DF	T2	SOT-353/ SC70-5/ SC-88A (Pb-Free)	178 mm, 3000 Unit
NL17SZU04XV5T2	NL	1	7	SZ	U04	XV5	T2	SOT-553*	178 mm, 4000 Unit

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *All Devices in Package SOT553 are Inherently Pb–Free.

NL17SZU04

PACKAGE DIMENSIONS

SOT-353 **DF SUFFIX** 5-LEAD PACKAGE CASE 419A-02 ISSUE G

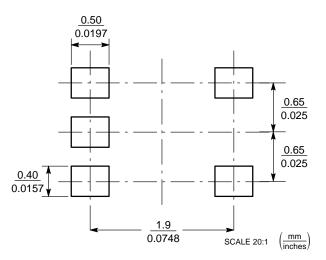


NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
К	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20



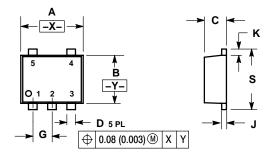


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NL17SZU04

PACKAGE DIMENSIONS

SOT-553 XV5 SUFFIX 5-LEAD PACKAGE CASE 463B-01 **ISSUE A**



NOTES:

- IDENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETERS
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS
- OF BASE MATERIAL

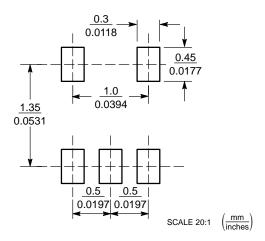
	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.50	1.70	0.059	0.067	
В	1.10	1.30	0.043	0.051	
С	0.50	0.60	0.020	0.024	
D	0.17	0.27	0.007	0.011	
G	0.50	BSC	0.020 BSC		
J	0.08	0.18	0.003	0.007	
Κ	0.10	0.30	0.004	0.012	
s	1.50	1.70	0.059	0.067	

STYL

PI

E 1:		STYLE 2:	
N 1.	BASE 1	PIN 1.	CATHODE
2.	EMITTER 1/2	2.	ANODE
3.	BASE 2	3.	CATHODE
4.	COLLECTOR 2	4.	CATHODE
5.	COLLECTOR 1	5.	CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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